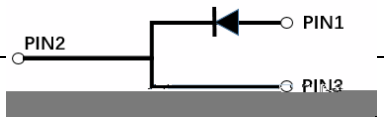
YJD106504PQG3Q



Silicon Carbide Schottky Diode

Features

Typical Applications

Mechanical Data

Package

Terminals

Polarity

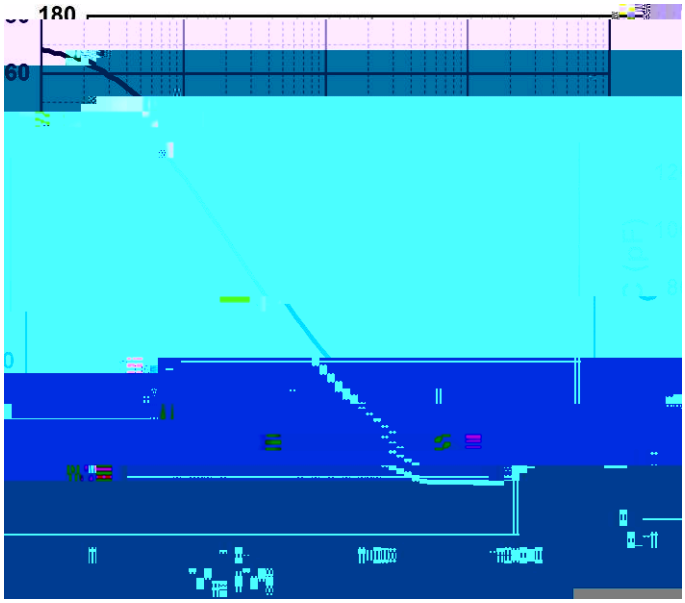
	∫

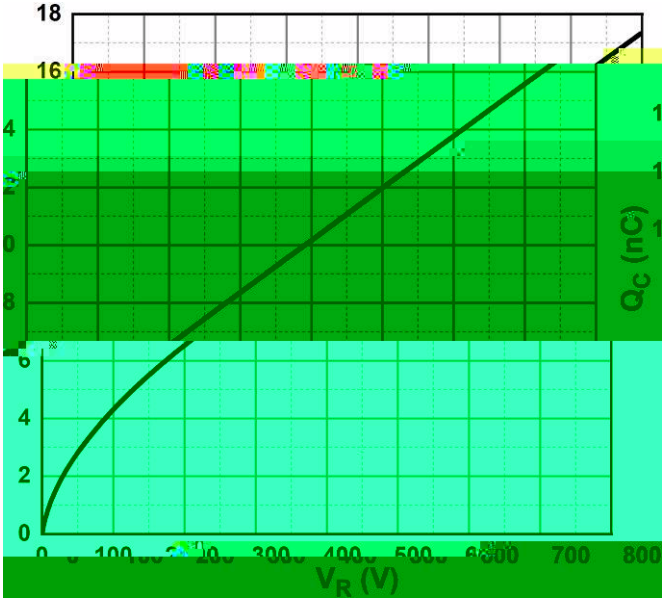
Maximum Ratings

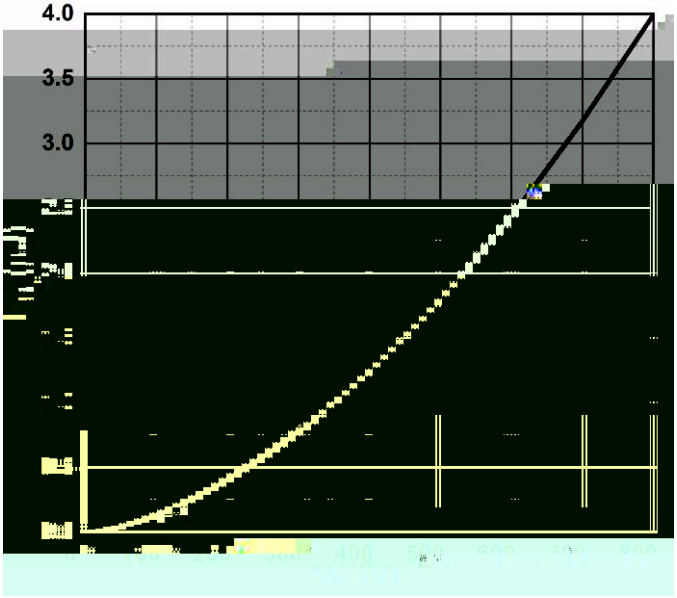
PARAMTETER	SYMBOL	UNIT	VALUE

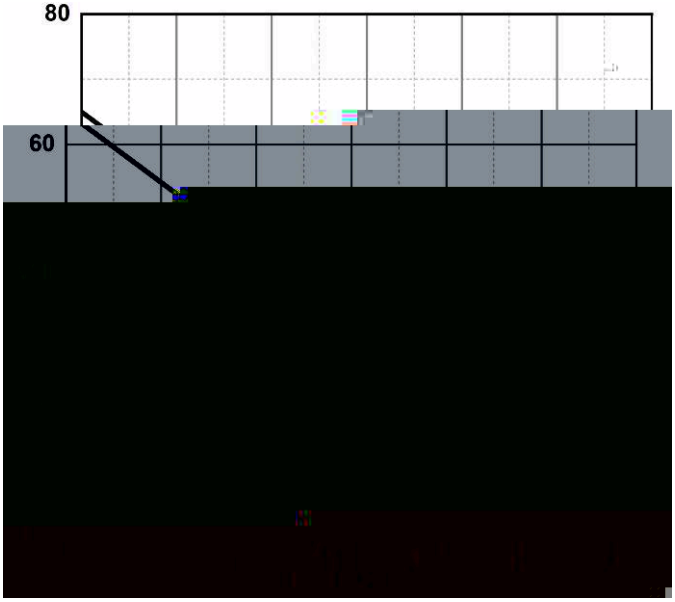
Electrical Characteristics

PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Typ.	Max.

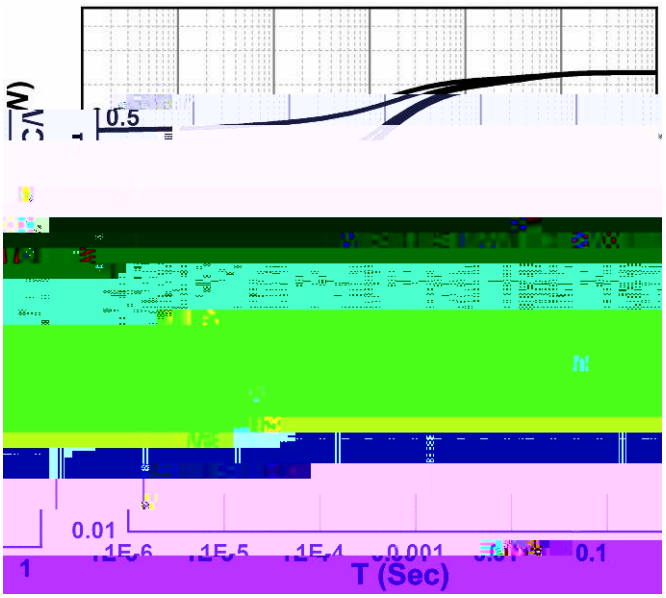

180
60


18
16
4
0
8
6
4
2
0
Q_C (nC)
700
800
V_R (V)

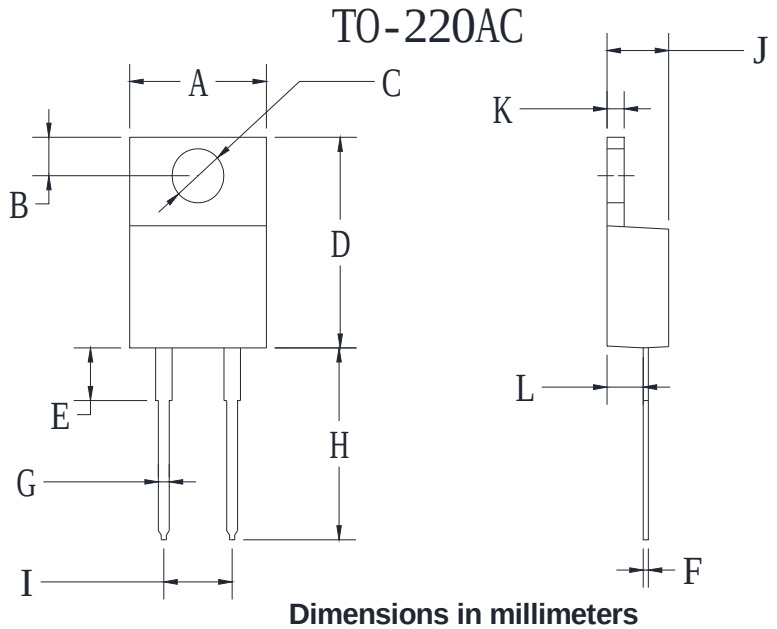

4.0
3.5
3.0


80
60

48


0.5
0.01
1
0.001
0.1
T (Sec)

Outline Dimensions



Dimensions in millimeters

TO-220AC		